



DMN3066LQ

### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BVDSS	RDS(ON) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	67mΩ @ V <sub>GS</sub> = 4.5V	3.6A
30V	$70m\Omega @ V_{GS} = 4.0V$	3.5A
	98mΩ @ Vgs = 2.5V	3.0A

## Description

This new generation MOSFET has been designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

Load Switch

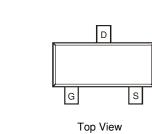
### **Features**

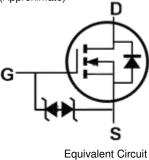
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3066LQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)





Pin-Out

Ordering Information (Note 4)

ESD Protected Gate

Part Number	Case	Packaging
DMN3066LQ-7	SOT23	3,000/Tape & Reel
DMN3066LQ-13	SOT23	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

BF5	ΨM
	'

SOT23

Top View

 $\frac{BF5}{YM} = \text{Product Type Marking Code}$  $\frac{YM}{Y} = \text{Date Code Marking}$  $\frac{Y}{Y} = \text{Year (ex: I = 2021)}$ M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	I	J	K	L	М	Ν	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	30	V
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ State $T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$			ID	3.6 2.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)		I <sub>DM</sub>	21	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.81	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	154	°C/W
Total Power Dissipation (Note 6)		PD	1.33	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	94	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

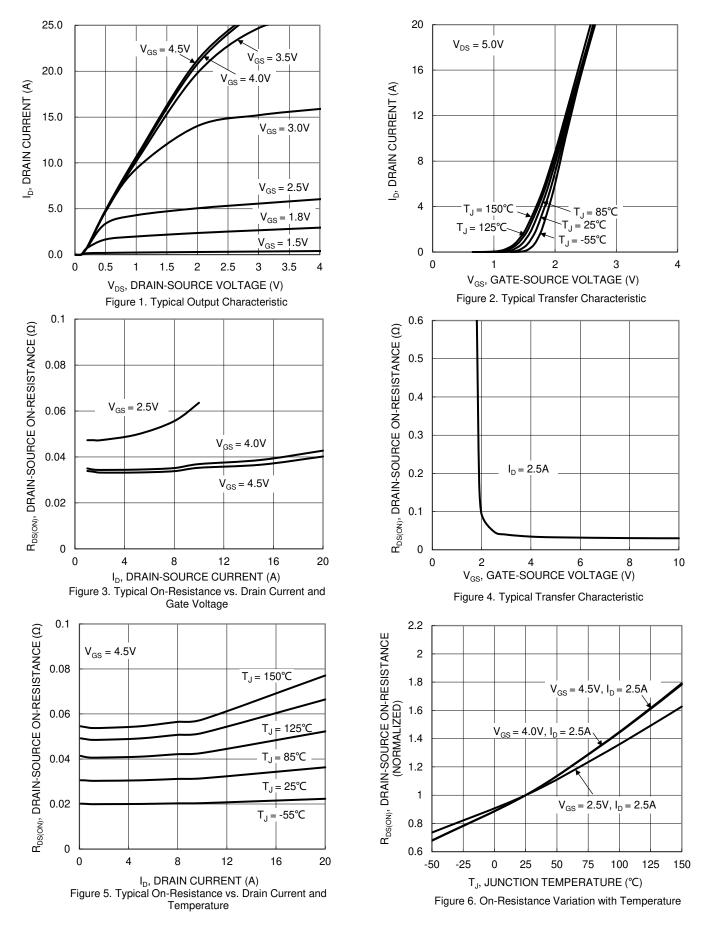
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						•
Drain-Source Breakdown Voltage	BVDSS	30			V	$V_{GS}=0V,\ I_D=250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	—		1.0	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	Igss	—		±10	μA	$V_{GS}=\pm 12V,V_{DS}=0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5		1.5	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			29	67		$V_{GS} = 4.5V, I_D = 2.5A$
Static Drain-Source On-Resistance	RDS(ON)	—	31	70	mΩ	$V_{GS}=4.0V,\ I_D=2.5A$
			43	98		$V_{GS} = 2.5V, I_D = 2.5A$
Diode Forward Voltage	Vsd	—	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 0.6A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	353		pF	
Output Capacitance	Coss	—	60		pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	42		pF	1 - 1.00012
Gate Resistance	Rg	_	4.7		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	—	4.1		nC	
Gate-Source Charge	Qgs	—	0.6		nC	VGS = 4.5V, VDS = 15V, ID = 2.5A
Gate-Drain Charge	Q <sub>gd</sub>	—	1.2		nC	1D = 2.3A
Turn-On Delay Time	td(on)		5.7	_	ns	
Turn-On Rise Time	tR	_	19		ns	VDD = 15V, ID = 1.25A, VGEN = 4.5V,
Turn-Off Delay Time	tD(OFF)		22	_	ns	$R_{GEN} = 4.5V$ , RGEN = 10 $\Omega$
Turn-Off Fall Time	t⊨		11	_	ns	7

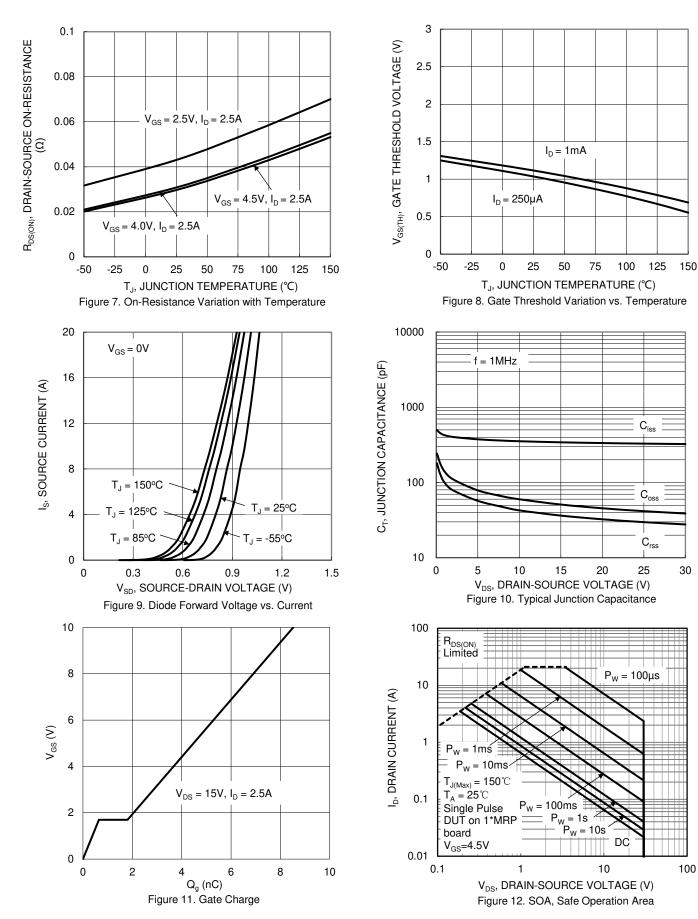
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing

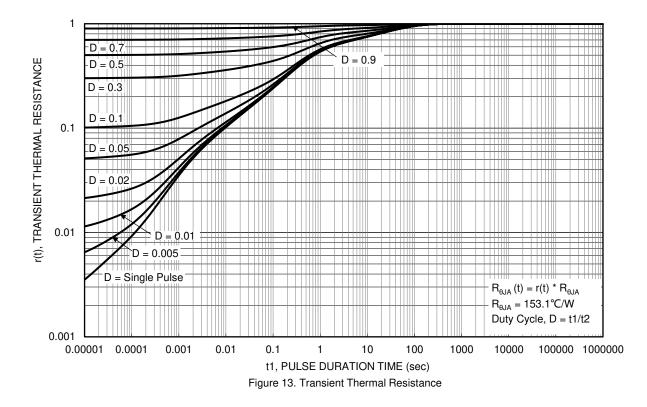








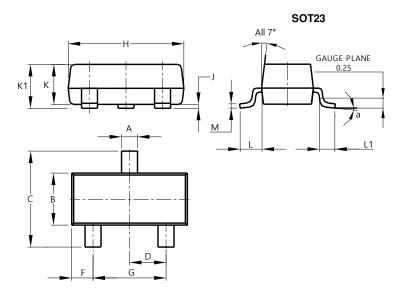






# Package Outline Dimensions

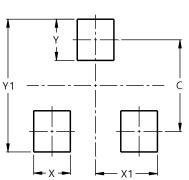
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
К	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	Dimens	ions in	mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23



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